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Mal-Soon Lee, Ferdinand P. Poudeu, and S. D. Mahanti

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This paper was published online on 17 February with an error in the denominator of Eq. (2). Equation (2) should read as

$$v_{\alpha\beta}(T, \mu) = \frac{1}{eT\Omega} \int \sigma_{\alpha\beta}(\varepsilon)(\varepsilon - \mu) \left[-\frac{\partial f_0(T, \varepsilon, \mu)}{\partial \varepsilon} \right] d\varepsilon. \quad (2)$$

The equation has been corrected as of 21 April 2011. The equation is incorrect in the printed version of the journal.